

RoHS

Phase Control Thyristors (Stud Version), 300 A



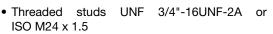
TO-118 (TO-209AE)

PRIMARY CHARACTERISTICS			
I _{T(AV)}	300 A		
V _{DRM} /V _{RRM}	400 V, 800 V, 1200 V, 1600 V, 1800 V, 2000 V		
V_{TM}	1.28 V		
I _{GT}	200 mA		
TJ	-40 °C to +125 °C		
Package	TO-118 (TO-209AE)		
Circuit configuration	Single SCR		

FEATURES

- Center amplifying gate
- International standard case TO-118 (TO-209AE)





- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		300	А		
I _{T(AV)}	T _C	75	°C		
I _{T(RMS)}		470			
	50 Hz	8000	Α		
ITSM	60 Hz	8380	1		
l ² t	50 Hz	320	kA ² s		
1-1	60 Hz	292			
V _{DRM} /V _{RRM}		400 to 2000	V		
tq	Typical	100	μs		
T _J		-40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM MA			
	04	400	500				
	08	800	900				
VS-ST300S	12	1200	1300	50			
V3-313003	16	1600	1700	50			
	18	1800	1900				
	20	2000	2100				



ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	1	180° conduction, half sine wave		300	Α	
at case temperature	$I_{T(AV)}$				75	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 64 °C	case temperat	ure	470	
		t = 10 ms	No voltage		8000	
Maximum peak, one-cycle	L	t = 8.3 ms	reapplied		8380	A
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		6730	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	7040	
Maximum I ² t for fusing		t = 10 ms No voltage	No voltage	initial $T_J = T_J$ maximum	320	- kA ² s
	l ² t	t = 8.3 ms	reapplied		292	
		t = 10 ms	100 % V _{RRM}		226	
		t = 8.3 ms	reapplied		207	
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms t	o 10 ms, no volt	age reapplied	3200	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x \mid_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.97	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		0.74	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.73	11152	
Maximum on-state voltage	V_{TM}	$I_{pk} = 940 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.66	V	
Maximum holding current	I _H	T 25 °C	anada supply 1	2 V resistive lead	600	mA
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	IIIA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0	-10
Typical turn-off time	t _q	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA



TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES		UNITS
PANAMETEN	STIVIDOL	16	31 CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T. – T. maximum	t < 5 mg	2	20	V
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		5	.0	v
		T _J = -40 °C		200	-	
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Manipulation and a set of this and a	100	200	mA
		T _J = 125 °C	Maximum required gate trigger/ current/voltage are the lowest	50	-	
		T _J = -40 °C	value which will trigger all units 12 V anode to cathode applied	2.5	-	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 v anode to camode applied	1.8	3	٧
	T _J = 125 °C		1.1	-		
DC gate current not to trigger	I _{GD}	T T massimas um	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V_{GD}	T _J = T _J maximum value which will not triggorn unit with rated V _{DRM} anocathode applied		0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	T_J		-40 to 125	- °C	
Maximum storage temperature range	T _{Stg}		-40 to 150		
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.10	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.03] ^K / VV	
Mounting torque, ± 10 %		Non-lubricated threads	48.5 (425)	$N \cdot m$ (lbf \cdot in)	
Approximate weight			535	g	
Case style		See dimensions - link at the end of datasheet	TO-118 (TO-	209AE)	

△R _{thJC} CONDUCTIO	N			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.011	0.008		
120°	0.013	0.014		
90°	0.017	0.018	$T_J = T_J$ maximum	K/W
60°	0.025	0.026		
30°	0.041	0.042		

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

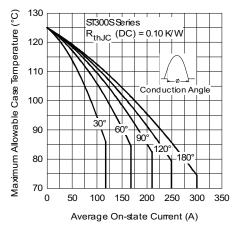


Fig. 1 - Current Ratings Characteristics

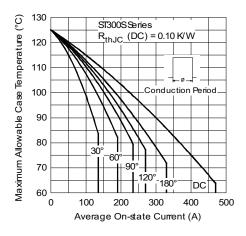


Fig. 2 - Current Ratings Characteristics

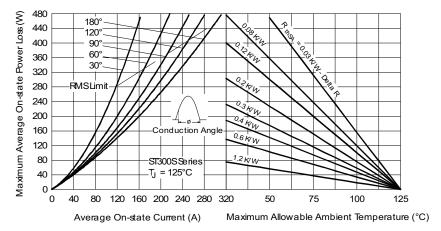


Fig. 3 - On-State Power Loss Characteristics

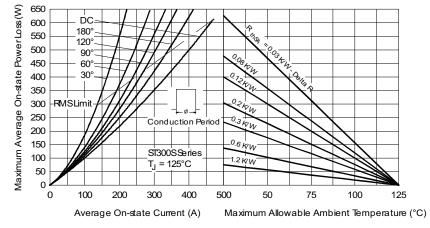


Fig. 4 - On-State Power Loss Characteristics

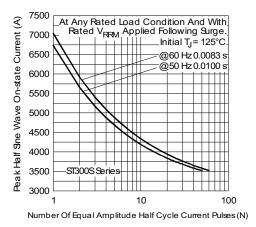


Fig. 5 - Maximum Non-Repetitive Surge Current

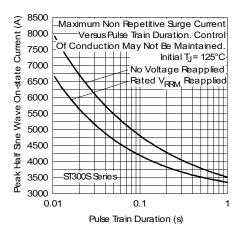


Fig. 6 - Maximum Non-Repetitive Surge Current

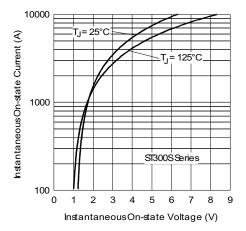


Fig. 7 - On-State Voltage Drop Characteristics

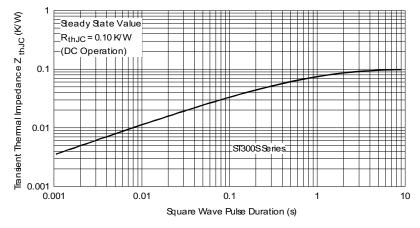


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

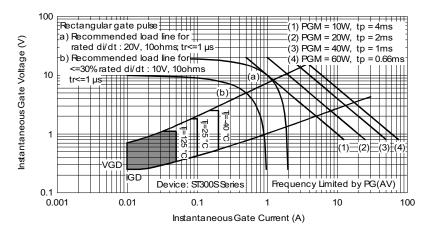
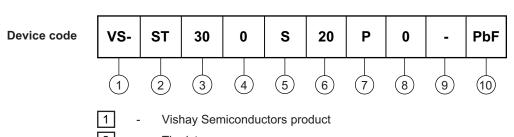


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE



2 - Thyristor

3 - Essential part number

4 - 0 = Converter grade

5 - S = Compression bonding stud

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - P = stud base 3/4" 16UNF-2A threads

M = stud base metric threads (M24 x 1.5)

8 - 0 = Eyelet terminals (gate and auxiliary cathode leads)

1 = Fast-on terminals (gate and auxiliary cathode leads)

3 = Threaded top terminal 3/8" 24UNF-2A

9 - Critical dV/dt: • None = 500 V/µs (standard value)

• L = 1000 V/µs (special selection)

10 - None = Standard production

- PbF = Lead (Pb)-free

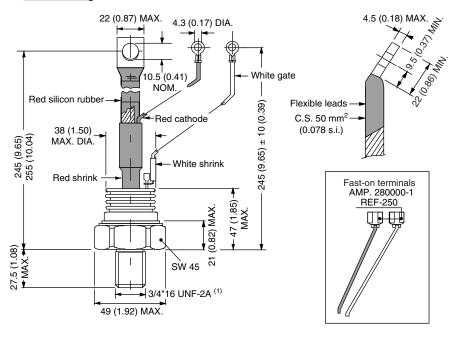
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95084	



TO-209AE (TO-118)

DIMENSIONS - TO-209AE (TO-118) in millimeters (inches)

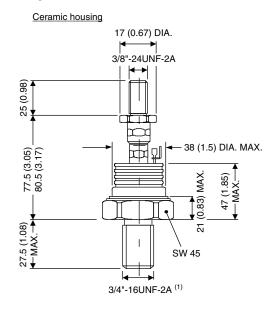
Ceramic housing



Note

 $^{(1)}$ For metric device: M24 x 1.5 - length screw 21 (0.83) maximum

DIMENSIONS - TO-209AE (TO-118) WITH TOP THREAD TERMINAL 3/8" in millimeters (inches)



Note

 $^{(1)}$ For metric device: M24 x 1.5 - length screw 21 (0.83) maximum

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